

L Number	Hits	Search Text	DB	Time stamp
1	1052	(349/5,110).CCLS.	USPAT; US-PGPUB	2004/03/09 10:09
2	231	((349/5,110).CCLS.) and (light adj2 valve)	USPAT; US-PGPUB	2004/03/09 10:10
3	14	((349/5,110).CCLS.) and (light adj2 valve)) and (semiconductor adj2 substrate)	USPAT; US-PGPUB	2004/03/09 10:12
4	4598	light adj2 valve	EPO; JPO; DERWENT	2004/03/09 10:13
5	2437	(light adj2 valve) and (liquid adj2 crystal)	EPO; JPO; DERWENT	2004/03/09 10:13
6	23	((light adj2 valve) and (liquid adj2 crystal)) and (semiconductor adj2 substrate)	EPO; JPO; DERWENT	2004/03/09 10:14
-	1	("6139162").PN.	USPAT	2002/06/18 10:54
-	1	("5907373").PN.	USPAT	2002/06/18 10:55
-	1	("5934778").PN.	USPAT	2002/06/18 10:55
-	1	("6038054").PN.	USPAT	2002/06/18 10:56
-	9808	("349").CLAS.	USPAT	2002/06/18 10:57
-	1144	((349/).CCLS.) and (light adj2 valve)	USPAT	2002/06/18 10:58
-	71	((349/).CCLS.) and (light adj2 valve)) and (semiconductor adj2 substrate)	USPAT	2002/06/18 10:58
-	9	((349/).CCLS.) and (light adj2 valve)) and (semiconductor adj2 substrate)) and (light adj2 shield)	USPAT	2002/10/15 07:31
-	27146	Hitachi.as.	USPAT	2002/10/12 12:34
-	1608	Hitachi.as. and sato	USPAT	2002/10/12 12:34
-	108	Hitachi.as. and hirota	USPAT	2002/10/12 12:35
-	11	(Hitachi.as. and sato) and (Hitachi.as. and hirota)	USPAT	2002/10/12 12:35
-	4	((Hitachi.as. and sato) and (Hitachi.as. and hirota)) and takemoto	USPAT	2002/10/12 12:35
-	3	((Hitachi.as. and sato) and (Hitachi.as. and hirota)) and takemoto) and matsumoto	USPAT	2002/10/12 12:35
-	2	6081305.URPN.	USPAT	2002/10/12 12:54
-	4	("5365355" "5461501" "5541748" "5574292").PN.	USPAT	2002/10/12 12:56
-	443	(349/110).CCLS.	USPAT	2002/10/12 13:00
-	0	("47 and (light adj2 valve)").PN.	USPAT	2002/10/12 13:00
-	46	((349/110).CCLS.) and (light adj2 valve)	USPAT	2002/10/12 13:01
-	1	((349/110).CCLS.) and (light adj2 valve)) and (light adj2 shield)) and (counter adj2 electrode)	USPAT	2002/10/12 13:04
-	11	((349/110).CCLS.) and (light adj2 valve)) and (light adj2 shield)	USPAT	2002/10/12 13:04
-	8	((349/).CCLS.) and (light adj2 valve)) and (semiconductor adj2 substrate)) and (light adj2 shield) and (insulating adj2 layer)	USPAT	2002/10/15 07:32
-	3	((349/).CCLS.) and (light adj2 valve)) and (semiconductor adj2 substrate)) and (light adj2 shield) and (insulating adj2 layer)) and (Silicon adj2 dioxide)	USPAT	2002/10/15 07:33